



Data sheet acquired from Harris Semiconductor SCHS198C

November 1997 - Revised May 2003

# High Speed CMOS Logic Dual 4-Stage Static Shift Register

#### Features

- Maximum Frequency, Typically 60MHz
   C<sub>L</sub> = 15pF, V<sub>CC</sub> = 5V, T<sub>A</sub> = 25°C
- · Positive-Edge Clocking
- Overriding Reset
- · Buffered Inputs and Outputs
- Fanout (Over Temperature Range)
- Wide Operating Temperature Range ... -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
  - 2V to 6V Operation
  - High Noise Immunity:  $N_{IL}$  = 30%,  $N_{IH}$  = 30% of  $V_{CC}$  at  $V_{CC}$  = 5V

## Description

The 'HC4015 consists of two identical, independent, 4-stage serial-input/parallel-output registers. Each register has independent Clock (CP) and Reset (MR) inputs as well as a single serial Data input. "Q" outputs are available from each of the four stages on both registers. All register stages are D-type, master-slave flip-flops. The logic level present at the Data input is transferred into the first register stage and shifted over one stage at each positive- going clock transition. Resetting of all stages is accomplished by a high level on the reset line.

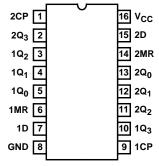
The device can drive up to 10 low power Schottky equivalent loads. The 'HC4015 is an enhanced version of equivalent CMOS types.

## **Ordering Information**

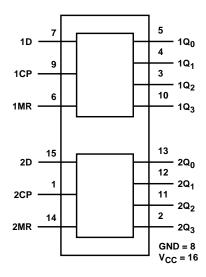
PART NUMBER	TEMP. RANGE (°C)	PACKAGE
CD54HC4015F3A	-55 to 125	16 Ld CERDIP
CD74HC4015E	-55 to 125	16 Ld PDIP
CD74HC4015M	-55 to 125	16 Ld SOIC

#### **Pinout**

CD54HC4015 (CERDIP) CD74HC4015 (PDIP, SOIC) TOP VIEW



# Functional Diagram



#### **TRUTH TABLE**

	INPUTS		OUTPUTS						
СР	D	R	Q <sub>0</sub>	Q <sub>1</sub>	Q <sub>2</sub>	$Q_3$			
1	I	L	L	q' <sub>0</sub>	q' <sub>1</sub>	q' <sub>2</sub>			
1	h	L	Н	q' <sub>0</sub>	q' <sub>1</sub>	q' <sub>2</sub>			
$\downarrow$	Х	L	q'o	q' <sub>1</sub>	q' <sub>2</sub>	q'3			
Х	Х	Н	L	L	L	L			

H = High Voltage Level

h = High Voltage Level One Set-up Time Prior to the Low to High Clock Transition

L = Low Voltage Level

I = Low Voltage Level One Set-up Time Prior to the Low to High Clock Transition

X = Don't Care.

↑ = Low to High Clock Transition

 $\downarrow$  = High to Low Clock Transition

 $q'_n$  = Lower case letters indicate the state of the referenced output one set-up time prior to the Low to High clock transition.

### CD54HC4015, CD74HC4015

#### **Absolute Maximum Ratings** Thermal Information $\theta_{JA}$ (°C/W) DC Supply Voltage, V<sub>CC</sub> .....-0.5V to 7V Thermal Resistance (Typical, Note 1) DC Input Diode Current, I<sub>IK</sub> M (SOIC) Package..... DC Output Diode Current, IOK For $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$ ......±20mA Maximum Storage Temperature Range .....-65°C to 150°C DC Output Source or Sink Current per Output Pin, IO Maximum Lead Temperature (Soldering 10s)......300°C For $V_O > -0.5V$ or $V_O < V_{CC} + 0.5V$ ...... $\pm 25$ mA (SOIC - Lead Tips Only) **Operating Conditions** Temperature Range, T<sub>A</sub> . . . . . . . . . . . . . . . . -55°C to 125°C Supply Voltage Range, V<sub>CC</sub> HC Types ......2V to 6V DC Input or Output Voltage, V<sub>I</sub>, V<sub>O</sub> . . . . . . . . . . . . . . 0V to V<sub>CC</sub> Input Rise and Fall Time 4.5V...... 500ns (Max)

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

#### NOTE

1. The package thermal impedance is calculated in accordance with JESD 51-7.

## **DC Electrical Specifications**

		TEST CONDITIONS		Vcc	V <sub>CC</sub> 25°C				-40°C TO 85°C		-55°C TO 125°C		
PARAMETER	SYMBOL	V <sub>I</sub> (V)	I <sub>O</sub> (mA)	(8)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS	
High Level Input	V <sub>IH</sub>	-	-	2	1.5	-	-	1.5	-	1.5	-	V	
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V	
				6	4.2	-	-	4.2	-	4.2	-	V	
Low Level Input	V <sub>IL</sub>	-	-	2	-	-	0.5	-	0.5	-	0.5	V	
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V	
				6	-	-	1.8	-	1.8	-	1.8	V	
High Level Output	V <sub>OH</sub>	V <sub>IH</sub> or V <sub>IL</sub>	-0.02	2	1.9	-	-	1.9	-	1.9	-	V	
Voltage CMOS Loads			-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V	
			-0.02	6	5.9	-	-	5.9	-	5.9	-	V	
High Level Output	7		-	-	-	-	-	-	-	-	-	V	
Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V	
			-5.2	6	5.48	-	-	5.34	-	5.2	-	V	
Low Level Output	V <sub>OL</sub>	V <sub>OL</sub>	V <sub>IH</sub> or V <sub>IL</sub>	0.02	2	-	-	0.1	-	0.1	-	0.1	V
Voltage CMOS Loads			0.02	4.5	-	-	0.1	-	0.1	-	0.1	V	
			0.02	6	-	-	0.1	-	0.1	-	0.1	V	
Low Level Output	1		-	-	-	-	-	-	-	-	-	V	
Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V	
7.12.25dd5			5.2	6	-	-	0.26	-	0.33	-	0.4	V	
Input Leakage Current	Ι <sub>Ι</sub>	V <sub>CC</sub> or GND	-	6	-	-	±0.1	-	±1	-	±1	μА	
Quiescent Device Current	Icc	V <sub>CC</sub> or GND	0	6	-	-	8	-	80	-	160	μА	

# CD54HC4015, CD74HC4015

# **Prerequisite for Switching Specifications**

			25	°С	-40°C T	O 85°C	-55°C T		
PARAMETER	SYMBOL	V <sub>CC</sub> (V)	MIN	MAX	MIN	MAX	MIN	MAX	UNITS
Maximum Clock	f <sub>MAX</sub>	2	6	-	5	-	4	-	MHz
Frequency		4.5	30	-	24	-	20	-	MHz
		6	35	-	28	-	24	-	MHz
Clock Pulse Width	t <sub>W</sub>	2	80	-	100	-	120	-	ns
		4.5	16	-	20	-	24	-	ns
		6	14	-	17	-	20	-	ns
MR Pulse Width	t <sub>W</sub>	2	150	-	190	-	225	-	ns
		4.5	30	-	38	-	45	-	ns
		6	26	-	33	-	38	-	ns
MR Recovery Time	t <sub>REC</sub>	2	50	-	65	-	75	-	ns
		4.5	10	-	13	-	15	-	ns
		6	9	-	11	-	13	-	ns
Set-up Time,	tsul, tsuh	2	60	-	75	-	90	-	ns
Data-In to CP		4.5	12	-	15	-	18	-	ns
		6	10	-	13	-	15	-	ns
Hold Time,	tH	2	0	-	0	-	0	-	ns
Data-In to CP		4.5	0	-	0	-	0	-	ns
		6	0	-	0	-	0	-	ns

# **Switching Specifications** Input $t_r$ , $t_f = 6ns$

	TEST V <sub>CC</sub> 25°C			-40°C T	O 85°C	-55°C TO 125°C					
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Propagation Delay (Figure 1)	t <sub>PLH,</sub>	C <sub>L</sub> = 50pF	2	-	-	175	-	220	-	270	ns
Clock to Q <sub>n</sub>	t <sub>PHL</sub>		4.5	-	-	35	-	44	-	54	ns
		C <sub>L</sub> =15pF	5	-	14	-	-	-	-	-	ns
		C <sub>L</sub> = 50pF	6	-	-	30	-	37	-	46	ns
MR to Q <sub>n</sub> , (Clock High)	t <sub>PLH</sub> ,	C <sub>L</sub> = 50pF	2	-	-	275	-	345	-	415	ns
	t <sub>PHL</sub>		4.5	-	-	55	-	64	-	83	ns
		C <sub>L</sub> =15pF			25	-	-	-	-	-	ns
		C <sub>L</sub> = 50pF	6	-	-	47	-	54	-	71	ns
MR to Q <sub>n</sub> , (Clock Low)	t <sub>PLH</sub> ,	C <sub>L</sub> = 50pF	2	-	-	325	-	400	-	490	ns
	t <sub>PHL</sub>		4.5	-	-	65	-	81	-	98	ns
		C <sub>L</sub> =15pF			25	-	-	-	-	-	ns
		C <sub>L</sub> = 50pF	6	-	-	55	-	69	-	83	ns
Output Transition Time	t <sub>TLH</sub> , t <sub>THL</sub>	C <sub>L</sub> = 50pF	2	-	-	75	-	95	-	110	ns
(Figure 1)			4.5	-	-	15	-	19	-	22	ns
			6	-	-	13	-	16	-	19	ns
Input Capacitance	C <sub>IN</sub>	C <sub>L</sub> = 50pF	-	-	-	10	-	10	-	10	pF
Maximum Clock Frequency	f <sub>MAX</sub>	C <sub>L</sub> =15pF	5	-	60	-	-	-	-	-	MHz
Power Dissipation Capacitance (Notes 2, 3)	C <sub>PD</sub>	C <sub>L</sub> =15pF	5	-	43	-	-	-	-	-	pF

- 2.  $C_{PD}$  is used to determine the dynamic power consumption, per shift register.

  3.  $P_D = V_{CC}^2 f_i + \sum C_L V_{CC}^2$  where  $f_i$  = Input Frequency,  $C_L$  = Output Load Capacitance,  $V_{CC}$  = Supply Voltage.

# Test Circuit and Waveform

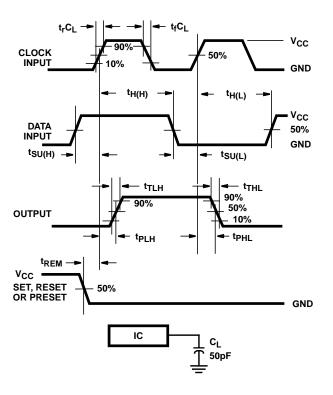


FIGURE 1. HC SETUP TIMES, HOLD TIMES, REMOVAL TIME, AND PROPAGATION DELAY TIMES FOR EDGE TRIGGERED SEQUENTIAL LOGIC CIRCUITS





ti.com 17-Oct-2005

#### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	n MSL Peak Temp <sup>(3)</sup>
5962-8995301EA	ACTIVE	CDIP	J	16	1	TBD	Call TI	Level-NC-NC-NC
CD54HC4015F3A	ACTIVE	CDIP	J	16	1	TBD	Call TI	Level-NC-NC-NC
CD74HC4015E	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD74HC4015EE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD74HC4015M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC4015ME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

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(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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#### 14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

# N (R-PDIP-T\*\*)

# PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN

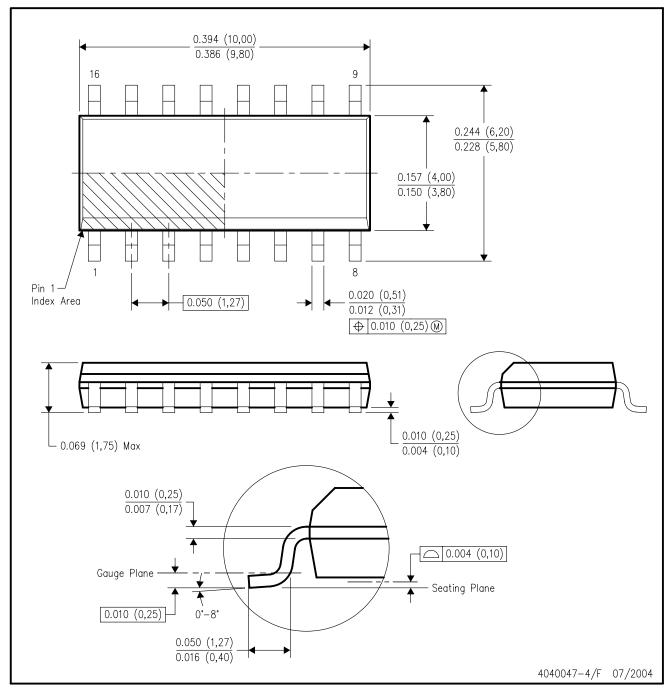


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



# D (R-PDSO-G16)

# PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-012 variation AC.



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